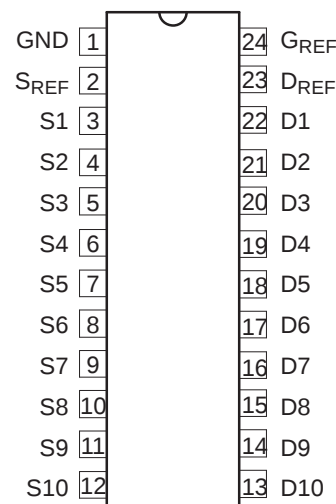


FEATURES

- Provides Bidirectional Voltage Translation With No Direction Control Required
- Allows Voltage Level Translation From 1 V up to 5 V
- Provides Direct Interface With GTL, GTL+, LVTTTL/TTL, and 5-V CMOS Levels
- Low On-State Resistance Between Input and Output Pins (Sn/Dn)
- Supports Hot Insertion
- No Power Supply Required – Will Not Latch Up
- 5-V-Tolerant Inputs
- Low Standby Current
- Flow-Through Pinout for Ease of Printed Circuit Board Trace Routing
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-4)
 - 1000-V Charged-Device Model (C101)

**PW PACKAGE
(TOP VIEW)**



APPLICATIONS

- Bidirectional or Unidirectional Applications Requiring Voltage-Level Translation From Any Voltage (1 V to 5 V) to Any Voltage (1 V to 5 V)
- Low Voltage Processor I²C Port Translation to 3.3-V and/or 5-V I²C Bus Signal Levels
- GTL/GTL+ Translation to LVTTTL/TTL Signal Levels

DESCRIPTION/ORDERING INFORMATION

The GTL2010 provides ten NMOS pass transistors (Sn and Dn) with a common gate (G_{REF}) and a reference transistor (S_{REF} and D_{REF}). The low ON-state resistance of the switch allows connections to be made with minimal propagation delay. With no direction control pin required, the device allows bidirectional voltage translations any voltage (1 V to 5 V) to any voltage (1 V to 5 V).

When the Sn or Dn port is LOW, the clamp is in the ON state and a low-resistance connection exists between the Sn and Dn ports. Assuming the higher voltage is on the Dn port, when the Dn port is HIGH, the voltage on the Sn port is limited to the voltage set by the reference transistor (S_{REF}). When the Sn port is HIGH, the Dn port is pulled to V_{CC} by the pullup resistors.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

DESCRIPTION/ORDERING INFORMATION (CONTINUED)

All transistors in the GTL2010 have the same electrical characteristics, and there is minimal deviation from one output to another in voltage or propagation delay. This offers superior matching over discrete transistor voltage-translation solutions where the fabrication of the transistors is not symmetrical. With all transistors being identical, the reference transistor (S_{REF}/D_{REF}) can be located on any of the other ten matched S_n/D_n transistors, allowing for easier board layout. The translator transistors with integrated ESD circuitry provides excellent ESD protection.

ORDERING INFORMATION

T_A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	TSSOP – PW	Tape and reel	SN74GTL2010PWR	GK2010

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

PIN DESCRIPTION

PIN NO.	NAME	DESCRIPTION
1	GND	Ground (0 V)
2	S_{REF}	Source of reference transistor
3–12	S_n	Ports S1–10
13–22	D_n	Ports D10–D1
23	D_{REF}	Drain of reference transistor
24	G_{REF}	Gate of reference transistor

FUNCTION TABLES⁽¹⁾

HIGH-to-LOW Translation (Assuming Dn is at the Higher Voltage Level)

$G_{REF}^{(2)}$	D_{REF}	S_{REF}	INPUTS D10–D1	OUTPUTS S10–S1	TRANSISTOR
H	H	0 V	X	X	Off
H	H	$V_{TT}^{(3)}$	H	$V_{TT}^{(4)}$	On
H	H	V_{TT}	L	L ⁽⁵⁾	On
L	L	$0 - V_{TT}$	X	X	Off

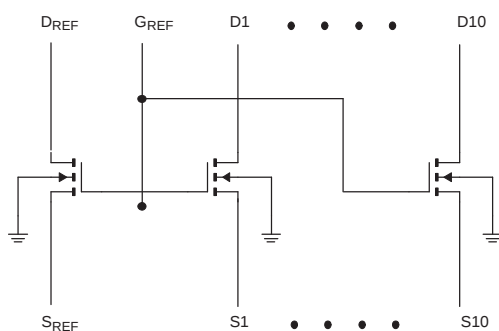
- (1) H = HIGH voltage level, L = LOW voltage level, X = don't care
(2) G_{REF} should be at least 1.5 V higher than S_{REF} for best translator operation.
(3) V_{TT} is equal to the S_{REF} voltage.
(4) Sn is not pulled up or pulled down.
(5) Sn follows the Dn input LOW.

LOW-to-HIGH Translation (Assuming Dn is at the Higher Voltage Level)⁽¹⁾

$G_{REF}^{(2)}$	D_{REF}	S_{REF}	INPUTS D10–D1	OUTPUTS S10–S1	TRANSISTOR
H	H	0 V	X	X	Off
H	H	$V_{TT}^{(3)}$	V_{TT}	H ⁽⁴⁾	Nearly off
H	H	V_{TT}	L	L ⁽⁵⁾	On
L	L	$0 - V_{TT}$	X	X	Off

- (1) H = HIGH voltage level, L = LOW voltage level, X = don't care
(2) G_{REF} should be at least 1.5 V higher than S_{REF} for best translator operation.
(3) V_{TT} is equal to the S_{REF} voltage.
(4) Dn is pulled up to V_{CC} through an external resistor.
(5) Dn follows the Sn input LOW.

CLAMP SCHEMATIC



SA00647

GTL2010

10-BIT BIDIRECTIONAL LOW-VOLTAGE TRANSLATOR

SCDS221 – SEPTEMBER 2006

Absolute Maximum Ratings⁽¹⁾⁽²⁾⁽³⁾

			MIN	MAX	UNIT
V _{SREF}	DC source reference voltage		–0.5	7	V
V _{DREF}	DC drain reference voltage		–0.5	7	V
V _{GREF}	DC gate reference voltage		–0.5	7	V
V _{Sn}	DC voltage port Sn		–0.5	7	V
V _{Dn}	DC voltage port Dn		–0.5	7	V
I _{REFK}	DC diode current on reference pins	V _I < 0 V		–50	mA
I _{SK}	DC diode current port Sn	V _I < 0 V		–50	mA
I _{DK}	DC diode current port Dn	V _I < 0 V		–50	mA
I _{MAX}	DC clamp current per channel	Channel in ON state		±128	mA
θ _{JA}	Package thermal impedance			88	°C/W
T _{stg}	Storage temperature range		–65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures that are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
- (3) The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

Recommended Operating Conditions

			MIN	MAX	UNIT
V _{I/O}	Input/output voltage (Sn, Dn)		0	5.5	V
V _{SREF}	DC source reference voltage ⁽¹⁾		0	5.5	V
V _{DREF}	DC drain reference voltage		0	5.5	V
V _{GREF}	DC gate reference voltage		0	5.5	V
I _{PASS}	Pass transistor current			64	mA
T _{amb}	Operating ambient temperature range (in free air)		–40	85	°C

- (1) V_{SREF} = V_{DREF} – 1.5 V for best results in level-shifting applications.

Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT	
V _{OL}	Low-level output voltage	V _{DD} = 3 V, V _{SREF} = 1.365 V, V _{Sn} or V _{Dn} = 0.175 V, I _{clamp} = 15.2 mA			260	350	mV	
V _{IK}	Input clamp voltage	I _I = −18 mA,	V _{GREF} = 0 V			−1.2	V	
I _{IH}	Gate input leakage	V _I = 5 V,	V _{GREF} = 0 V			5	μA	
C _{I(GREF)}	Gate capacitance	V _I = 3 V or 0 V			56		pF	
C _{IO(OFF)}	OFF capacitance	V _O = 3 V or 0 V,	V _{GREF} = 0 V		7.4		pF	
C _{IO(ON)}	ON capacitance	V _O = 3 V or 0 V,	V _{GREF} = 3 V		18.6		pF	
r _{on} ⁽²⁾	ON-state resistance	V _I = 0 V	V _{GREF} = 4.5 V	I _O = 64 mA		3.5	5	Ω
			V _{GREF} = 3 V			4.4	7	
			V _{GREF} = 2.3 V			5.5	9	
			V _{GREF} = 1.5 V			67	105	
			V _{GREF} = 1.5 V, I _O = 30 mA			9	15	
		V _I = 2.4 V	V _{GREF} = 4.5 V	I _O = 15 mA		7	10	
			V _{GREF} = 3 V			58	80	
		V _I = 1.7 V	V _{GREF} = 2.3 V			50	70	

(1) All typical values are measured at T_{amb} = 25°C.

(2) Measured by the voltage drop between the Sn and the Dn terminals at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (Sn or Dn) terminals.

AC Characteristics for Translator-Type Applications⁽¹⁾

$V_{REF} = 1.365\text{ V to }1.635\text{ V}$, $V_{DD1} = 3\text{ V to }3.6\text{ V}$, $V_{DD2} = 2.36\text{ V to }2.64\text{ V}$, $GND = 0\text{ V}$, $t_r = t_f \leq 3\text{ ns}$, $T_{amb} = -40^\circ\text{C to }85^\circ\text{C}$ (see Figure 5)

PARAMETER	MIN	TYP ⁽²⁾	MAX	UNIT
t_{PLH} ⁽³⁾ Propagation delay (Sn to Dn, Dn to Sn)	0.5	1.5	5.5	ns

(1) $C_{ON(max)}$ of 30 pF and a $C_{OFF(max)}$ of 15 pF is specified by design.

(2) All typical values are measured at $V_{DD1} = 3.3\text{ V}$, $V_{DD2} = 2.5\text{ V}$, $V_{REF} = 1.5\text{ V}$ and $T_{amb} = 25^\circ\text{C}$.

(3) Propagation delay specified by characterization.

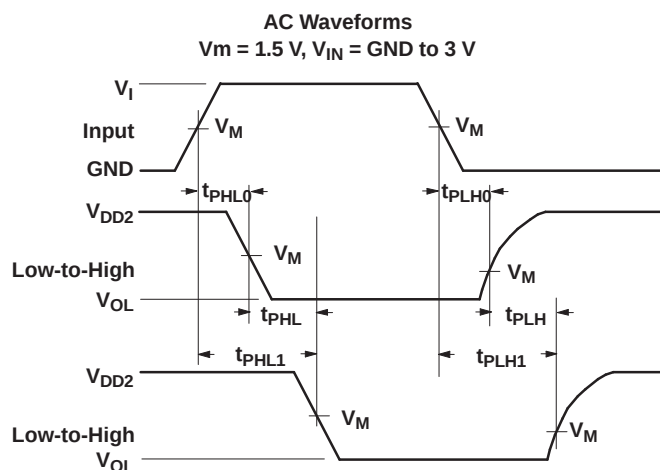


Figure 1. Input (Sn) to Output (Dn) Propagation Delays

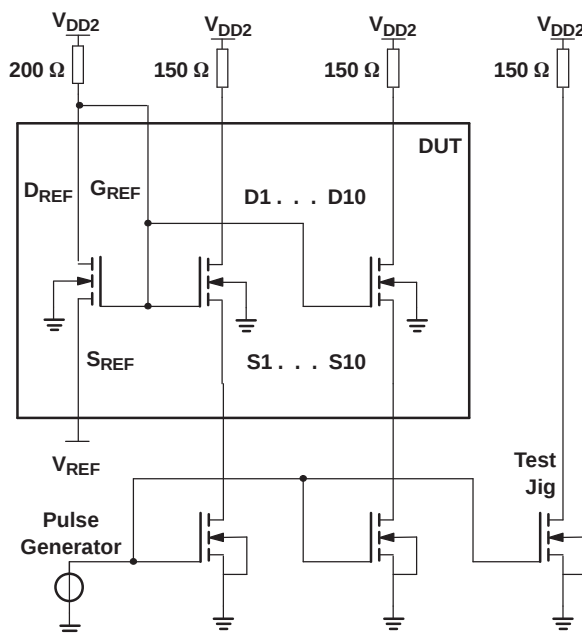


Figure 2. Load Circuit

AC Characteristics for CBT-Type Applications

$GND = 0\text{ V}$, t_R , $C_L = 50\text{ pF}$, $G_{REF} = 5\text{ V} \pm 0.5\text{ V}$, $T_{amb} = -40^\circ\text{C}$ to 85°C

PARAMETER		MIN	MAX	UNIT
t_{pd}	Propagation delay ⁽¹⁾		250	ps

- (1) This parameter is warranted but not production tested. The propagation delay is based on the RC time constant of the typical on-state resistance of the switch and a load capacitance of 50 pF, when driven by an ideal voltage source (zero output impedance).

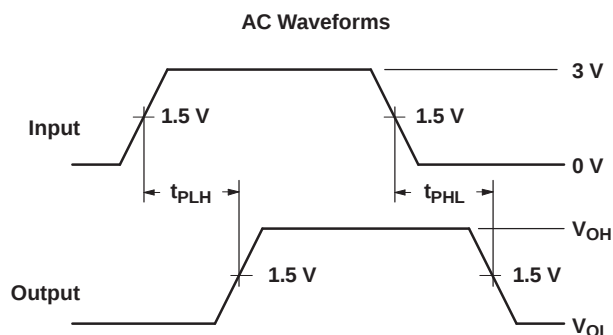
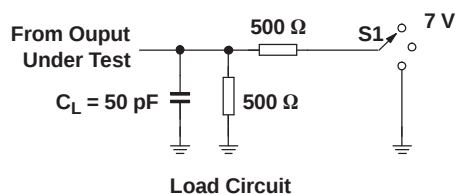


Figure 3. Input (S_n) to Output (D_n) Propagation Delays



TEST	S1
t_{pd}	Open
t_{PLZ}/t_{PZL}	7 V
t_{PHZ}/t_{PZH}	Open

C_L = Load capacitance, includes jig and probe capacitance (see *AC Characteristics* for value).

Figure 4. Load Circuit

APPLICATION INFORMATION

Bidirectional Translation

For the bidirectional clamping configuration (higher voltage to lower voltage or lower voltage to higher voltage), the G_{REF} input must be connected to D_{REF} and both pins pulled to HIGH-side V_{CC} through a pullup resistor (typically 200 k Ω). A filter capacitor on D_{REF} is recommended. The processor output can be totem pole or open drain (pullup resistors) and the chipset output can be totem pole or open drain (pullup resistors are required to pull the Dn outputs to V_{CC}). However, if either output is totem pole, data must be unidirectional or the outputs must be 3-statable, and the outputs must be controlled by some direction-control mechanism to prevent HIGH-to-LOW contentions in either direction. If both outputs are open drain, no direction control is needed. The opposite side of the reference transistor (S_{REF}) is connected to the processor core power-supply voltage. When D_{REF} is connected through a 200-k Ω resistor to a 3.3-V to 5.5-V V_{CC} supply and S_{REF} is set between 1 V to V_{CC} 1.5 V, the output of each Sn has a maximum output voltage equal to S_{REF} , and the output of each Dn has a maximum output voltage equal to V_{CC} .

APPLICATION INFORMATION (continued)

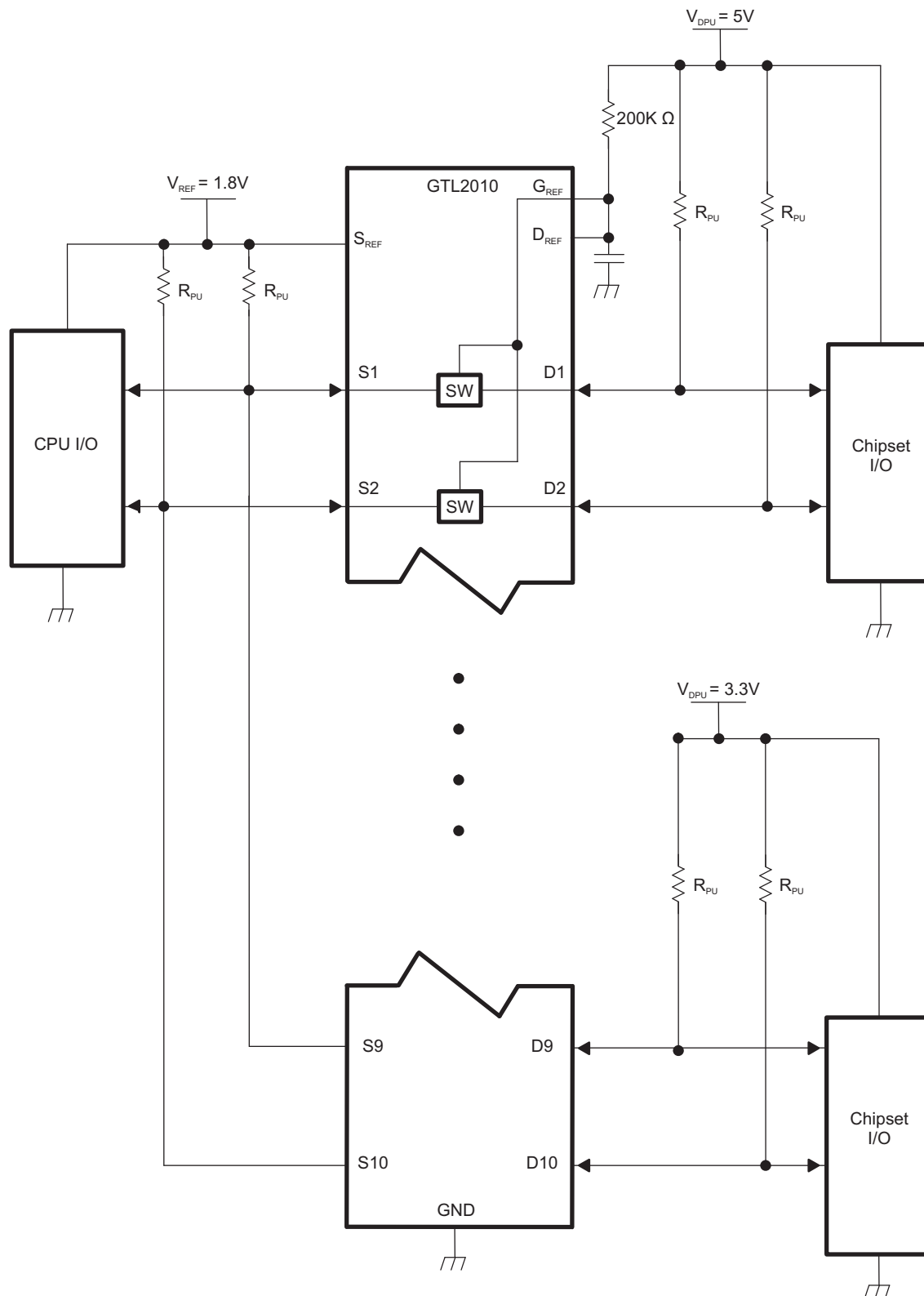


Figure 5. Bidirectional Translation to Multiple Higher Voltage Levels (Such as an I²C or SMBus Applications)

APPLICATION INFORMATION (continued)

Unidirectional Down Translation

For unidirectional clamping (higher voltage to lower voltage), the G_{REF} input must be connected to D_{REF} and both pins pulled to the higher-side V_{CC} through a pullup resistor (typically 200 k Ω). A filter capacitor on D_{REF} is recommended. Pullup resistors are required if the chipset I/Os are open drain. The opposite side of the reference transistor (S_{REF}) is connected to the processor core power-supply voltage. When D_{REF} is connected through a 200-k Ω resistor to a 3.3-V to 5.5-V V_{CC} supply and S_{REF} is set between 1 V to $V_{CC} - 1.5$ V, the output of each S_n has a maximum output voltage equal to S_{REF} .

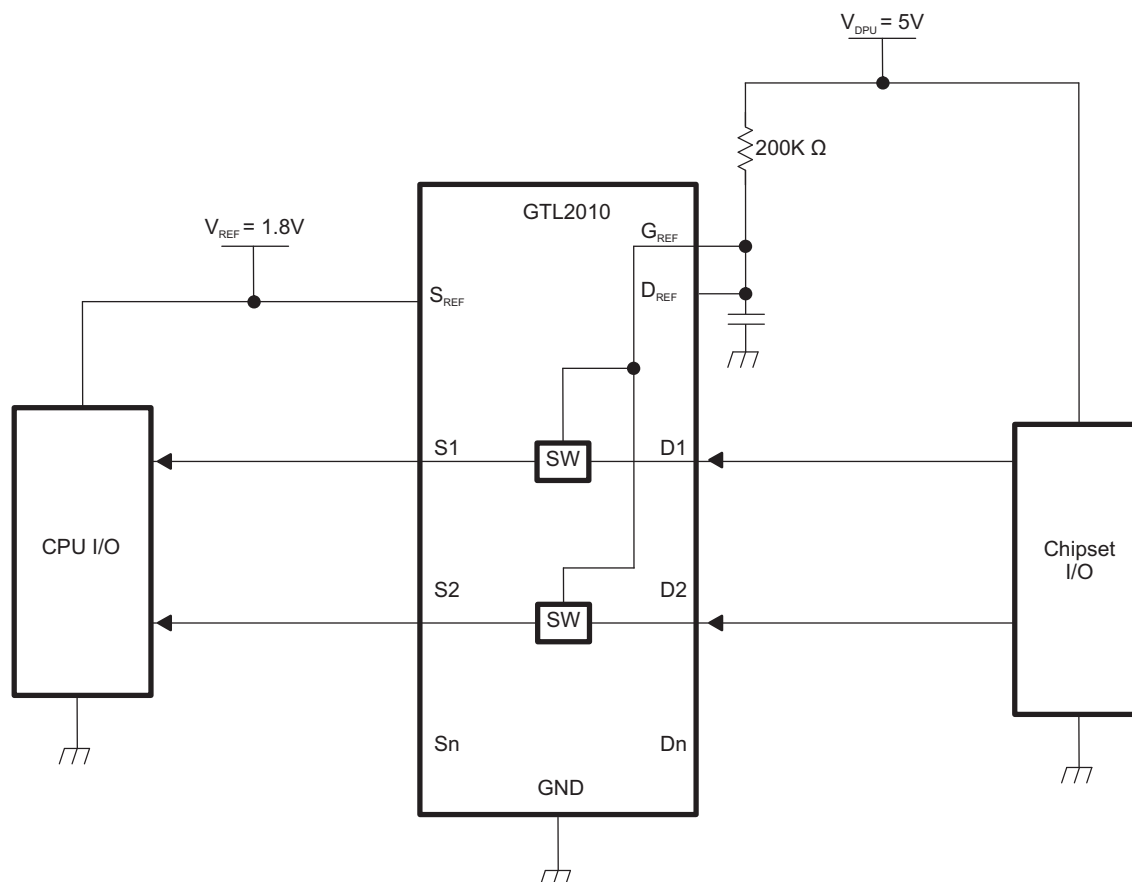


Figure 6. Unidirectional Down Translation to Protect Low-Voltage Processor Pins

APPLICATION INFORMATION (continued)

Unidirectional Up Translation

For unidirectional up translation (lower voltage to higher voltage), the reference transistor is connected the same as for a down translation. A pullup resistor is required on the higher voltage side (Dn or Sn) to get the full HIGH level, since the GTL device only passes the reference source (S_{REF}) voltage as a HIGH when doing an up translation. The driver on the lower voltage side only needs pullup resistors if it is open drain.

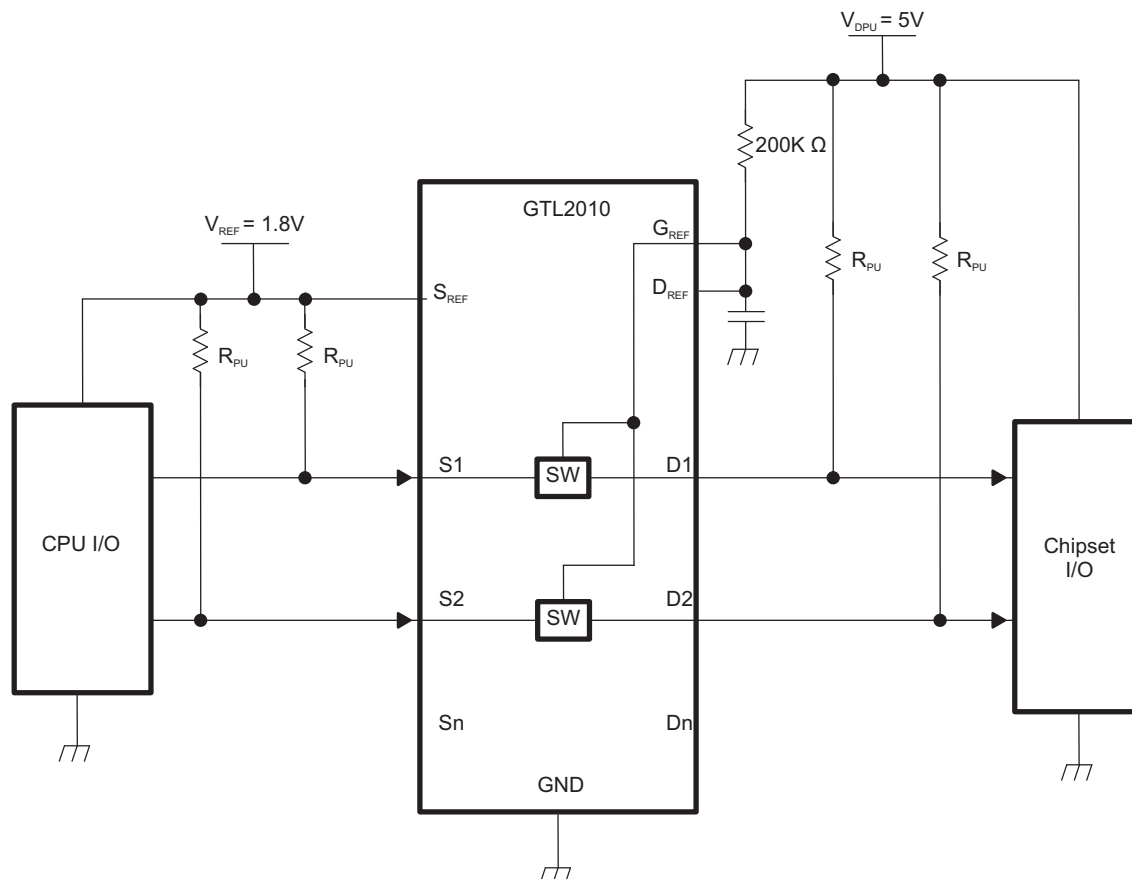


Figure 7. Unidirectional Up Translation to Higher-Voltage Chipsets

APPLICATION INFORMATION (continued)

Sizing Pullup Resistor

The pullup resistor value should limit the current through the pass transistor when it is in the on state to about 15 mA. This ensures a pass voltage of 260 mV to 350 mV. If the current through the pass transistor is higher than 15 mA, the pass voltage also is higher in the on state. To set the current through each pass transistor at 15 mA, the pullup resistor value is calculated as:

$$\text{Resistor value } (\Omega) = \frac{\text{Pullup voltage (V)} - 0.35 \text{ V}}{0.015 \text{ A}}$$

Table 1 shows resistor values for various reference voltages and currents at 15 mA, 10 mA, and 3 mA. The resistor value shown in the +10% column, or a larger value, should be used to ensure that the pass voltage of the transistor would be 350 mV or less. The external driver must be able to sink the total current from the resistors on both sides of the GTL device at 0.175 V, although the 15 mA only applies to current flowing through the GTL2010.

Table 1. Pullup Resistor Values⁽¹⁾⁽²⁾⁽³⁾

PULLUP RESISTOR VALUE (Ω)						
VOLTAGE	15 mA		10 mA		3 mA	
	NOMINAL	+10%	NOMINAL	+10%	NOMINAL	+10%
5.0 V	310	341	465	512	1550	1705
3.3 V	197	217	295	325	983	1082
2.5 V	143	158	215	237	717	788
1.8 V	97	106	145	160	483	532
1.5 V	77	85	115	127	383	422
1.2 V	57	63	85	94	283	312

(1) Calculated for $V_{OL} = 0.35 \text{ V}$

(2) Assumes output driver $V_{OL} = 0.175 \text{ V}$ at stated current

(3) +10% to compensate for V_{DD} range and resistor tolerance

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN74GTL2010PW	Active	Production	TSSOP (PW) 24	60 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	GK2010
SN74GTL2010PW.A	Active	Production	TSSOP (PW) 24	60 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	GK2010
SN74GTL2010PWR	Active	Production	TSSOP (PW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	GK2010
SN74GTL2010PWR.A	Active	Production	TSSOP (PW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	GK2010

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74GTL2010PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

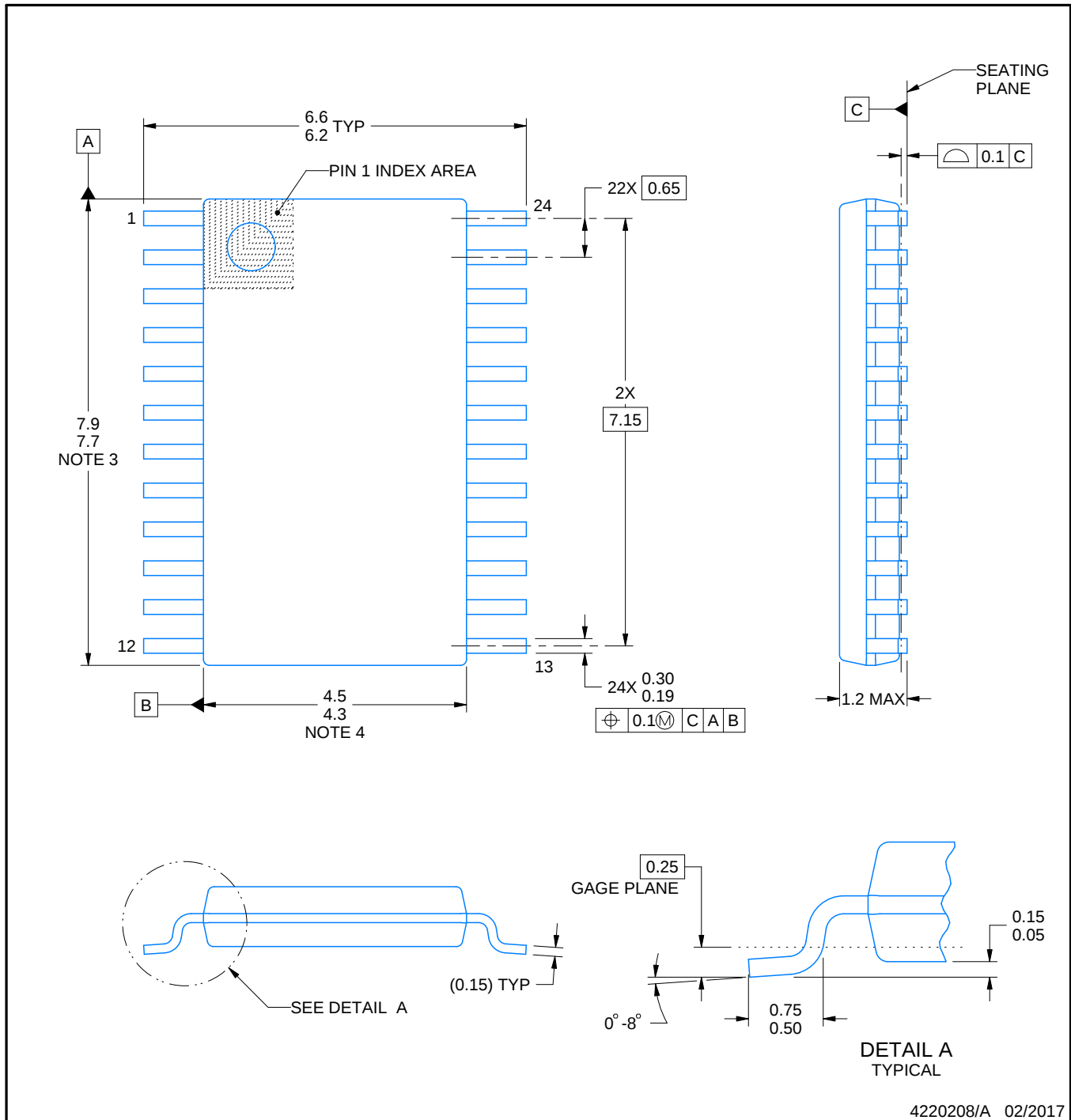
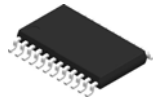
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74GTL2010PWR	TSSOP	PW	24	2000	353.0	353.0	32.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
SN74GTL2010PW	PW	TSSOP	24	60	530	10.2	3600	3.5
SN74GTL2010PW.A	PW	TSSOP	24	60	530	10.2	3600	3.5



4220208/A 02/2017

NOTES:

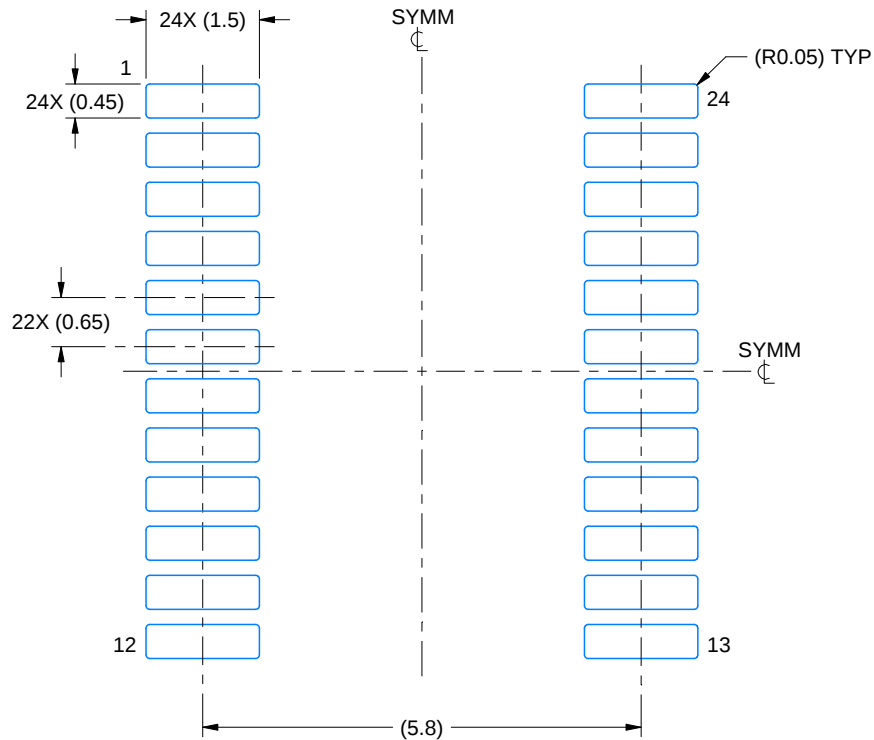
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

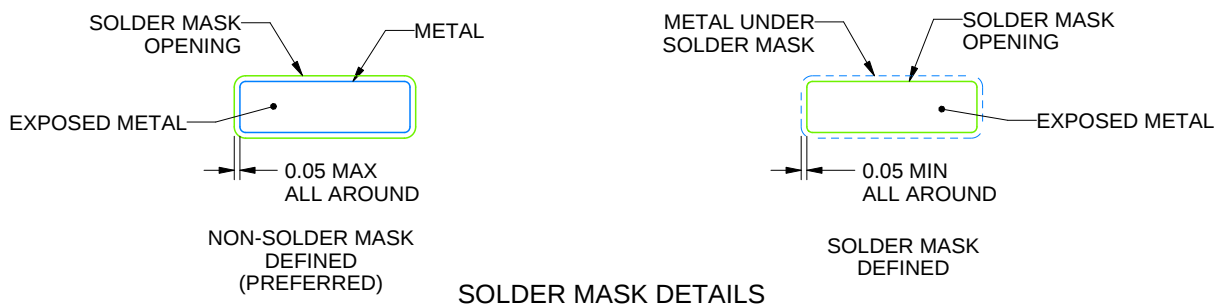
PW0024A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



4220208/A 02/2017

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

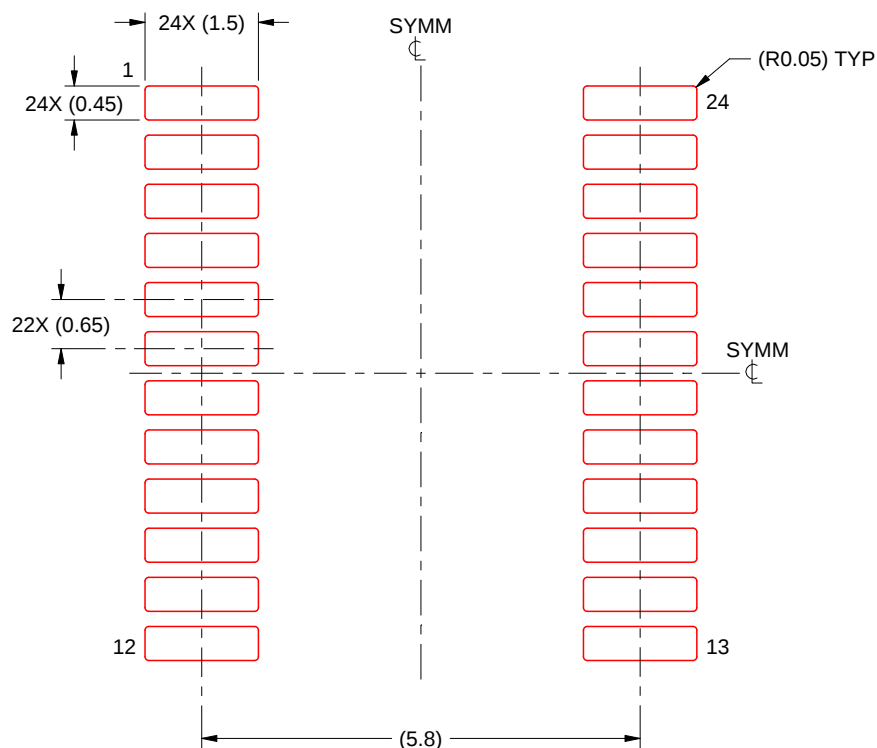
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0024A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220208/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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